74HC112; 74HCT112

Dual JK flip-flop with set and reset; negative-edge trigger

Rev. 3 — 9 August 2016 Product data sheet

1. General description

The 74HC112; 74HCT112 is a dual negative-edge triggered JK flip-flop. It features individual J and K inputs, clock (n \overline{CP}) set (n \overline{SD}) and reset (n \overline{RD}) inputs. It also has complementary nQ and n \overline{Q} outputs. The set and reset are asynchronous active LOW inputs and operate independently of the clock input. The J and K inputs control the state changes of the flip-flops as described in the mode select function table. The J and K inputs must be stable one set-up time prior to the HIGH-to-LOW clock transition for predictable operation. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

2. Features and benefits

- Input levels:
 - ◆ For 74HC112: CMOS level
 - ◆ For 74HCT112: TTL level
- Asynchronous set and reset
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

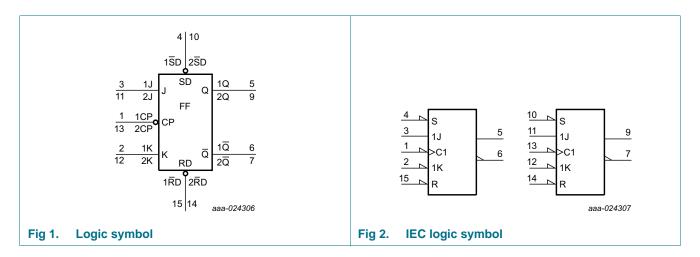
3. Ordering information

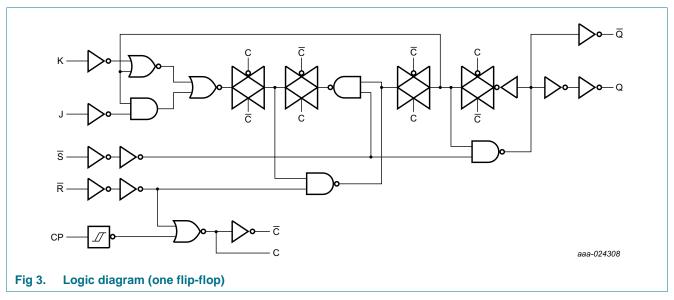
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC112D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT112D	-			
74HC112DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width	SOT338-1
74HCT112DB	-		5.3 mm	
74HC112PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74HCT112PW	-		body width 4.4 mm	



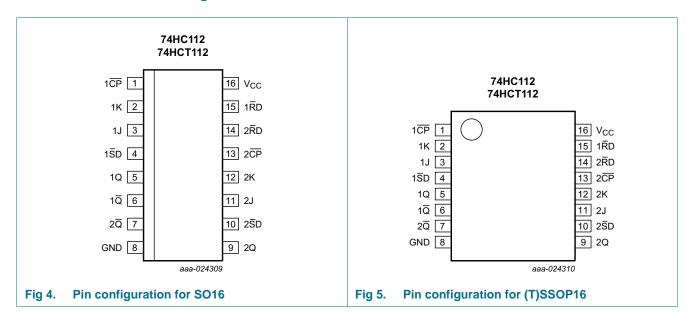
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP, 2CP	1, 13	clock input (HIGH-to-LOW; edge-triggered)
1K, 2K	2, 12	data input
1J, 2J	3, 11	data input
1SD, 2SD	4, 10	set input (active LOW)
1Q, 2Q	5, 9	true flip-flop output
1Q, 2Q	6, 7	complement flip-flop output
GND	8	ground (0 V)
1RD, 2RD	15, 14	reset input (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function selection[1]

Operating modes	Input					Output	Output		
	nSD	nRD	nCP	nJ	nK	nQ	nQ		
Asynchronous set	L	Н	Х	Х	Х	Н	L		
Asynchronous reset	Н	L	Х	Х	Х	L	Н		
Undetermined	L	L	Х	Х	Х	Н	L		
Toggle	Н	Н	\	h	h	q	q		
Load 0 (reset)	Н	Н	\downarrow	I	h	L	Н		
Load 1 (set)	Н	Н	\	h	I	Н	L		
Hold no change	Н	Н	\	I	I	q	q		

^[1] If nSD and nRD simultaneously go from LOW-to-HIGH, the output states are unpredictable.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO16 and (T)SSOP16 packages	<u>[1]</u>	-	500	mW

^[1] For SO16 packages: above 70 °C, the value of P_{tot} derates linearly with 8 mW/K. For (T)SSOP16 packages: above 60 °C, the value of P_{tot} derates linearly with 5.5 mW/K.

H = HIGH voltage level

 $h = HIGH \ voltage \ level \ one \ set-up \ time \ before \ the \ HIGH-to-LOW \ clock \ transition$

L = LOW voltage level

I = LOW voltage level one set-up time before the HIGH-to-LOW clock transition

q = lowercase letters indicate the state of the referenced output one set-up time before the HIGH-to-LOW clock transition

X = don't care

^{↓ =} HIGH-to-LOW clock transition

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC112		7	2	Unit	
			Min	Тур	Max	Min	Тур	Max	_
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	,	-40 °C t	o +85 °C	–40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC112	2									
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	8.0	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	4.0	-	40	-	80	μΑ

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	;	–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT11	12									
V_{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 5.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	4.0	-	40	-	80	μА
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		nSD inputs	-	50	180	-	225	-	245	μΑ
		nK inputs	-	60	216	-	270	-	294	μΑ
		nRD inputs	-	65	236	-	293	-	319	μΑ
		nJ, and nCP inputs	-	100	360	-	450	-	490	μΑ
C _I	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 8.

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
74HC112	2									
t _{pd}	propagation	nCP to nQ; see Figure 6 [2]								
•	delay	V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
		nCP to nQ; see Figure 6								
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		V _{CC} = 5 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
		nRD to nQ, nQ; see Figure 7								
		V _{CC} = 2.0 V	-	58	180	-	225	-	270	ns
		V _{CC} = 4.5 V	-	21	36	-	45	-	54	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	18	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	17	31	-	38	-	46	ns
		\overline{NSD} to \overline{NQ} ; see Figure 7								
		V _{CC} = 2.0 V	-	50	155	-	295	-	235	ns
		V _{CC} = 4.5 V	-	18	31	-	39	-	47	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	40	ns
t _t	transition	nQ, nQ; see Figure 6								
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _W	pulse width	nCP HIGH or LOW; see Figure 6								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		nSD, nRD LOW; see Figure 7								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see Figure 8.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t _{rec}	recovery time	nRD to nCP; see Figure 7								
		V _{CC} = 2.0 V	80	22	-	125	-	150	-	ns
		V _{CC} = 4.5 V	16	8	-	25	-	30	-	ns
		V _{CC} = 6.0 V	14	6	-	21	-	26	-	ns
		nSD to nCP; see Figure 7								
		V _{CC} = 2.0 V	80	-19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	-7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	-6	-	17	-	20	-	ns
t _{su}	set-up time	nJ and nK to nCP; see Figure 6								
		V _{CC} = 2.0 V	80	19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
t _h	hold time	nJ and nK to nCP; see Figure 6								
		V _{CC} = 2.0 V	0	-11	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-4	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-3	-	0	-	0	-	ns
f _{max}	maximum	nCP; see Figure 6								
	frequency	V _{CC} = 2.0 V	6	20	-	4.8	-	4.0	-	MHz
		V _{CC} = 4.5 V	30	60	-	24	-	20	-	MHz
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	66	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	71	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	-	27	-			-	-	pF

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit, see Figure 8.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
74HCT1	12							1		
t _{pd}	propagation	nCP to nQ; see Figure 6	1							
	delay	V _{CC} = 4.5 V	-	21	35	-	44	-	53	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		nCP to nQ; see Figure 6	1							
		V _{CC} = 4.5 V	-	23	40	-	50	-	60	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		\overline{nRD} to \overline{nQ} ;								
		see Figure 7								
		V _{CC} = 4.5 V	-	22	37	-	46	-	56	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		\overline{NSD} to \overline{NQ} ; see Figure 7								
		V _{CC} = 4.5 V	-	18	32	-	40	-	48	ns
		V _{CC} = 5 V; C _L = 15 pF	-	15	-	-	-	-	-	ns
t _t	transition	nQ, nQ; see Figure 6	1							
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	nCP HIGH or LOW; see Figure 6								
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		nSD, nRD LOW; see Figure 7								
		V _{CC} = 4.5 V	18	10	-	23	-	27	-	ns
t _{rec}	recovery time	nRD to nCP; see Figure 7								
		V _{CC} = 4.5 V	20	11	-	25	-	30	-	ns
		nSD to nCP; see Figure 7								
		V _{CC} = 4.5 V	20	-8	-	25	-	30	-	ns
t _{su}	set-up time	nJ and nK to nCP; see Figure 6								
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
t _h	hold time	nJ and nK to nCP; see Figure 6								
		V _{CC} = 4.5 V	0	-7	-	0	-	0	-	ns
f _{max}	maximum	nCP; see Figure 6								
	frequency	V _{CC} = 4.5 V	30	64	-	24	-	20	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	70	-	-	-	-	-	MHz

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 8.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _{PD}		$C_L = 50 \text{ pF}; f = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	-	30	-	-	-	-	-	pF

- [1] All typical values are measured at T_{amb} = 25 °C.
- [2] $\ t_{pd}$ is the same as t_{PLH} and $t_{PHL}.$
- [3] t_t is the same as t_{THL} and t_{TLH} .
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

11. Waveforms

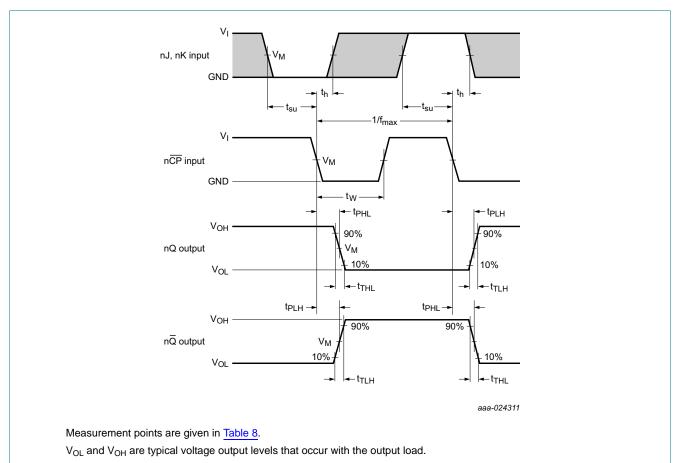


Fig 6. Clock propagation delays, output transition time, pulse width, set-up, hold times, and maximum frequency

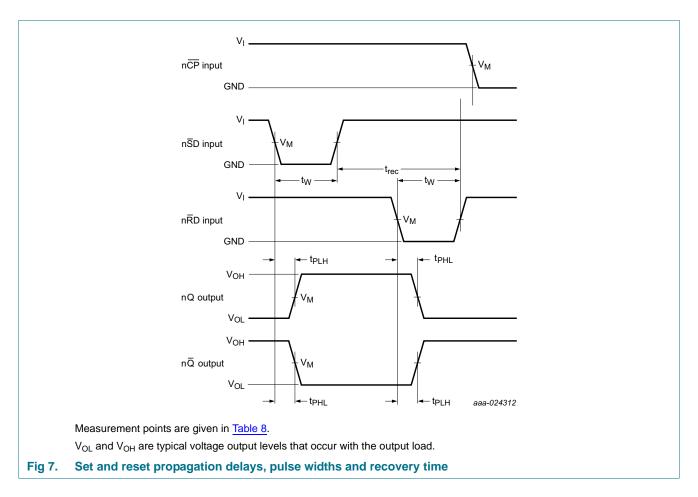
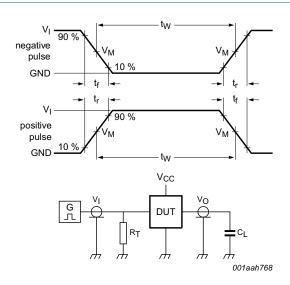


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74HC112	0.5V _{CC}	0.5V _{CC}
74HCT112	1.3 V	1.3 V



Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

Fig 8. Test circuit for measuring switching times

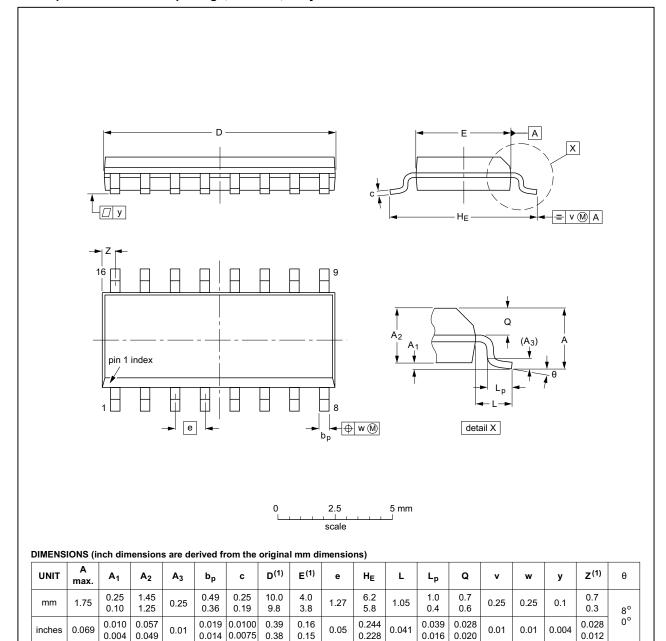
Table 9. Test data

Туре	Input		Load	Test
	VI	t _r , t _f	CL	
74HC112	V _{CC}	6 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT112	3 V	6 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19

Fig 9. Package outline SOT109-1 (SO16)

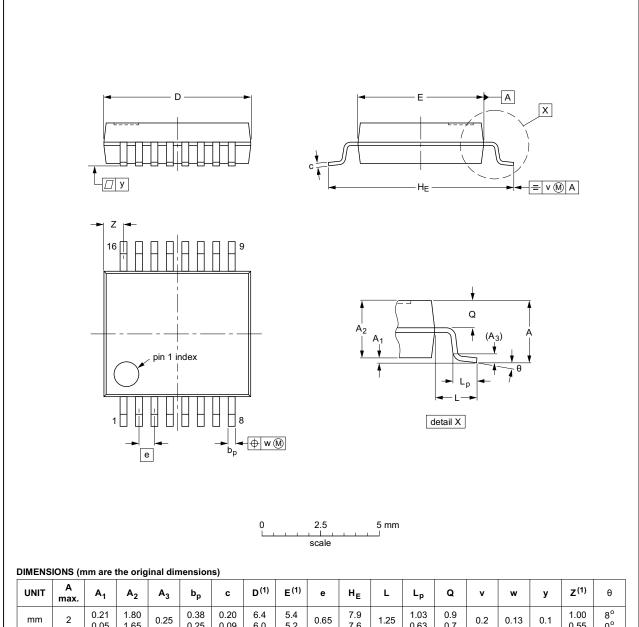
74HC_HCT112

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT338-1		MO-150			99-12-27 03-02-19	

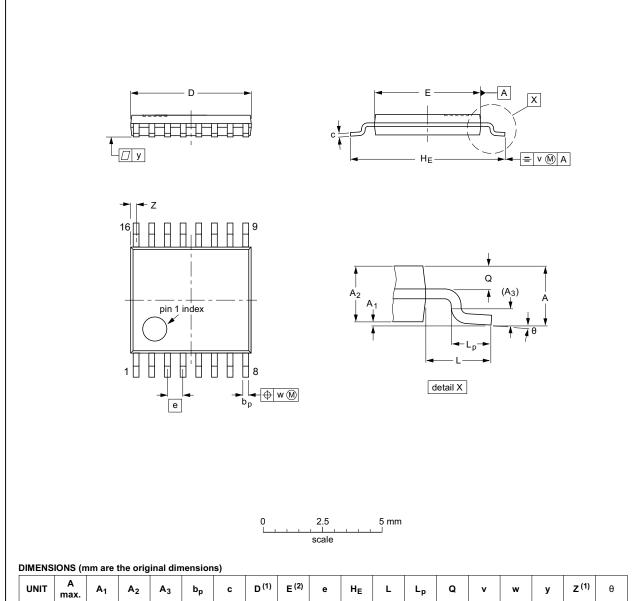
Fig 10. Package outline SOT338-1 (SSOP16)

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT403-1		MO-153			99-12-27 03-02-18	

Fig 11. Package outline SOT403-1 (TSSOP16)

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74HC_HCT112 v.3	20160809	Product data sheet	-	74HC_HCT112_CNV v.2				
Modifications:		 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 						
	Legal texts	have been adapted to the	new company name v	vhere appropriate.				
	Type numbers 74HC112N and 74HCT112N removed.							
74HC_HCT112_CNV v.2	19980610	Product specification	-	-				

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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